

Title (en)

FLASH MEMORY DEVICE AND FLASH MEMORY PROGRAMMING METHOD EQUALIZING WEAR-LEVEL

Title (de)

FLASH-SPEICHERANORDNUNG UND FLASH-SPEICHERPROGRAMMIERVERFAHREN MIT ENTZERRUNG DES ABNUTZUNGSWERTS

Title (fr)

DISPOSITIF À MÉMOIRE FLASH ET PROCÉDÉ DE PROGRAMMATION DE MÉMOIRE FLASH ÉGALISANT UN NIVEAU D'USURE

Publication

EP 2232501 A4 20110511 (EN)

Application

EP 08793470 A 20080825

Priority

- KR 2008004965 W 20080825
- KR 20070139108 A 20071227

Abstract (en)

[origin: WO2009084797A1] Disclosed are a flash memory device and flash memory programming method that equalizes a wear-level. The flash memory device includes a memory cell array, an inversion determining unit to generate a programming page through inverting or not inverting a data page based on a number of '1's and '0's in the data page, a programming unit to store the generated programming page in the memory cell array; and a data verifying unit to read the programming page stored in the memory cell array, to restore the data page from the programming page according to whether an error exists in the read programming page, and to output the restored data page, and thereby can equalize a wear-level of a memory cell.

IPC 8 full level

G11C 16/34 (2006.01); **G06F 12/02** (2006.01)

CPC (source: EP KR US)

G06F 3/0679 (2013.01 - US); **G06F 11/00** (2013.01 - US); **G06F 11/0727** (2013.01 - US); **G06F 11/08** (2013.01 - US); **G06F 12/0246** (2013.01 - US); **G06F 16/1847** (2018.12 - EP US); **G11C 11/5628** (2013.01 - US); **G11C 13/0035** (2013.01 - US); **G11C 16/06** (2013.01 - KR); **G11C 16/10** (2013.01 - EP KR US); **G11C 16/26** (2013.01 - EP US); **G11C 16/34** (2013.01 - KR); **G11C 16/3436** (2013.01 - US); **G11C 16/344** (2013.01 - US); **G11C 16/349** (2013.01 - EP US); **G11C 16/3495** (2013.01 - US); **G11C 29/36** (2013.01 - US); **G11C 2211/5647** (2013.01 - EP US)

Citation (search report)

- [XA] US 5270979 A 19931214 - HARARI ELIYAHOU [US], et al
- [XA] US 6292868 B1 20010918 - NORMAN ROBERT D [US]
- See references of WO 2009084797A1

Designated contracting state (EPC)

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